

RJH60M2DPE

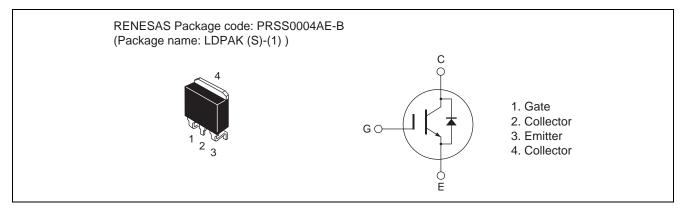
600V - 12A - IGBT Application: Inverter R07DS0531EJ0300 Rev.3.00 May 25, 2012

Features

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.9$ V typ. (at I_C = 12 A, V_{GE} = 15 V, Ta = 25°C)
- Built in fast recovery diode (85 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 45$ ns typ. (at $V_{CC} = 300$ V, $V_{GE} = 15$ V, $I_C = 12$ A, Rg = 5 Ω , $Ta = 25^{\circ}C$, inductive load)

Outline



Absolute Maximum Ratings

			<u> </u>	$(Ta = 25^{\circ}C)$
ltem		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	Ι _C	25	А
	Tc = 100°C	Ι _C	12	А
Collector peak current		ic(peak) Note1	36	А
Collector to emitter diode forward current		i _{DF}	12	А
Collector to emitter diode forward peak current		i _{DF} (peak) ^{Note1}	45	А
Collector dissipation		P _C ^{Note2}	63	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	1.98	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	2.8	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tc = 25°C



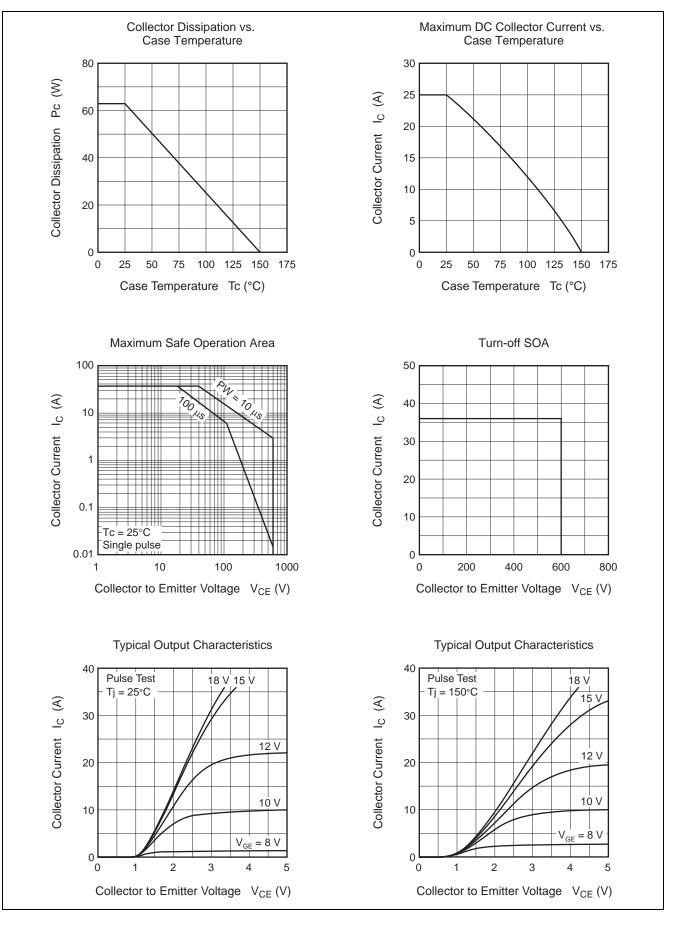
Electrical Characteristics

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	V _{(BR)CES}	600	—	—	V	$Iy = 10 \ \mu A, \ V_{GE} = 0$	
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	—	5	μA	$V_{CE} = 600 \text{ V}, \text{ V}_{GE} = 0$	
Gate to emitter leak current	I _{GES}	_	—	±1	μA	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$	
Gate to emitter cutoff voltage	V _{GE(off)}	5	—	7	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.9	2.5	V	$I_{C} = 12 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.8	_	V	$I_{C} = 25 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	430	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	40	_	pF	$V_{GE} = 0$	
Reverse transfer capacitance	Cres		15	_	pF	f = 1 MHz	
Total gate charge	Qg		33	_	nC	V _{GE} = 15 V	
Gate to emitter charge	Qge		5	_	nC	V _{CE} = 300 V	
Gate to collector charge	Qgc		19	_	nC	I _C = 12 A	
Turn-on delay time	t _{d(on)}		32	_	ns	V _{CC} = 300 V	
Rise time	tr		18	_	ns	V _{GE} = 15 V	
Turn-off delay time	t _{d(off)}	_	70	—	ns	$I_{C} = 12 A$ Rg = 5 Ω Inductive load	
Fall time	t _f	_	45	—	ns		
Turn-on energy	Eon	_	0.18	—	mJ		
Turn-off energy	E _{off}	_	0.18	—	mJ		
Total switching energy	E _{total}	_	0.36	—	mJ	1	
Short circuit withstand time	t _{sc}	6	8	—	μS	$\label{eq:CC} \begin{array}{l} \mbox{Tc} = 100 \ ^{\circ}\mbox{C} \\ \mbox{V}_{\mbox{CC}} \ \leq 360 \ \mbox{V}, \ \mbox{V}_{\mbox{GE}} = 15 \ \mbox{V} \end{array}$	
FRD Forward voltage	VF		1.2	1.6	V	$I_F = 12 \text{ A}^{\text{Note3}}$	
FRD reverse recovery time	t _{rr}	_	85	_	ns	I _F = 12 A	
FRD reverse recovery charge	Q _{rr}	_	0.14	_	μC	di _F /dt = 100 A/µs	
FRD peak reverse recovery current	-sii Irr		4.2		A	-	

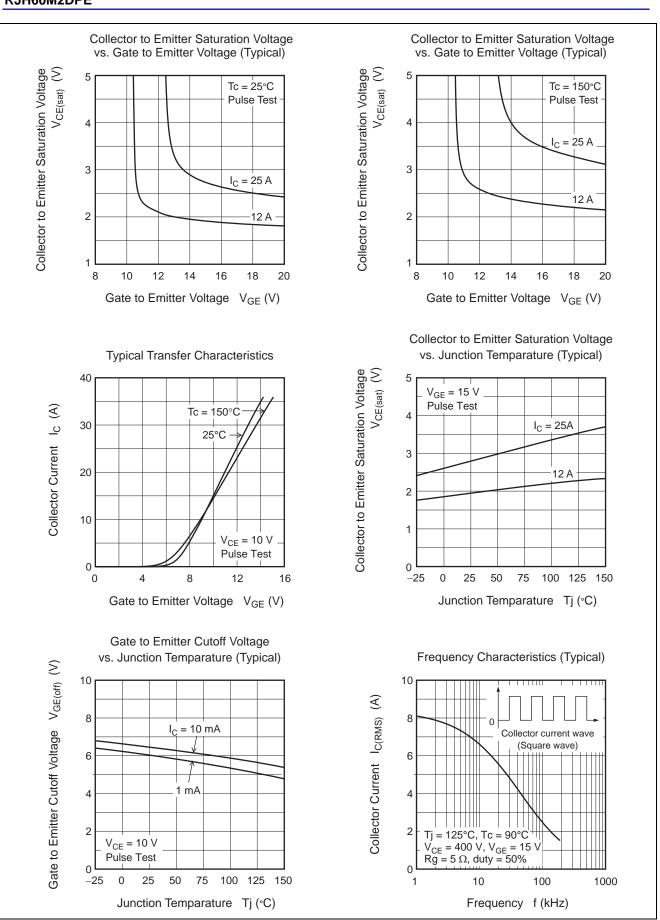
Notes: 3. Pulse test.



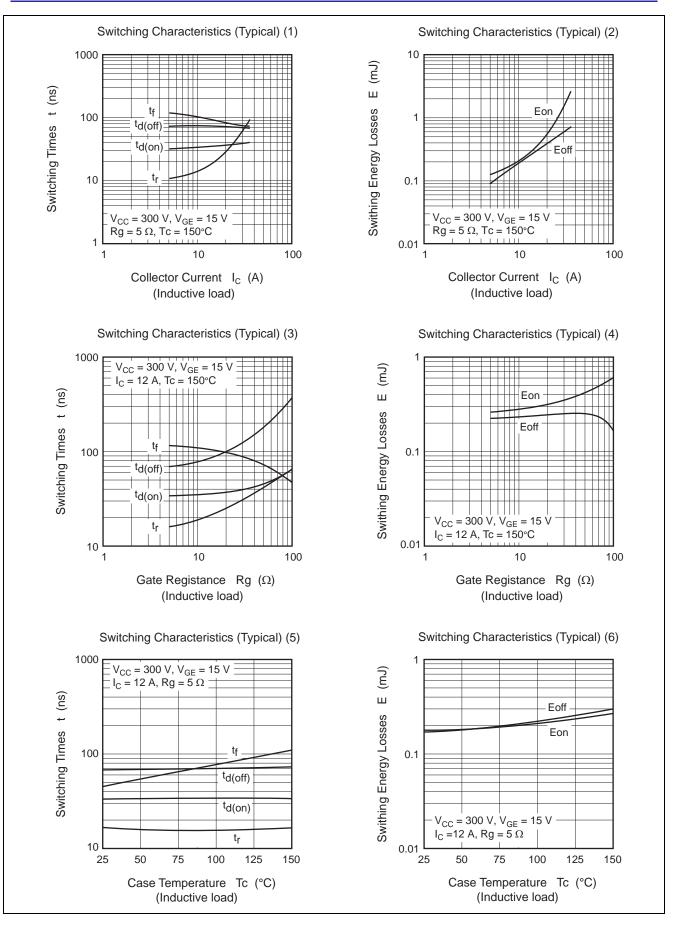
Main Characteristics

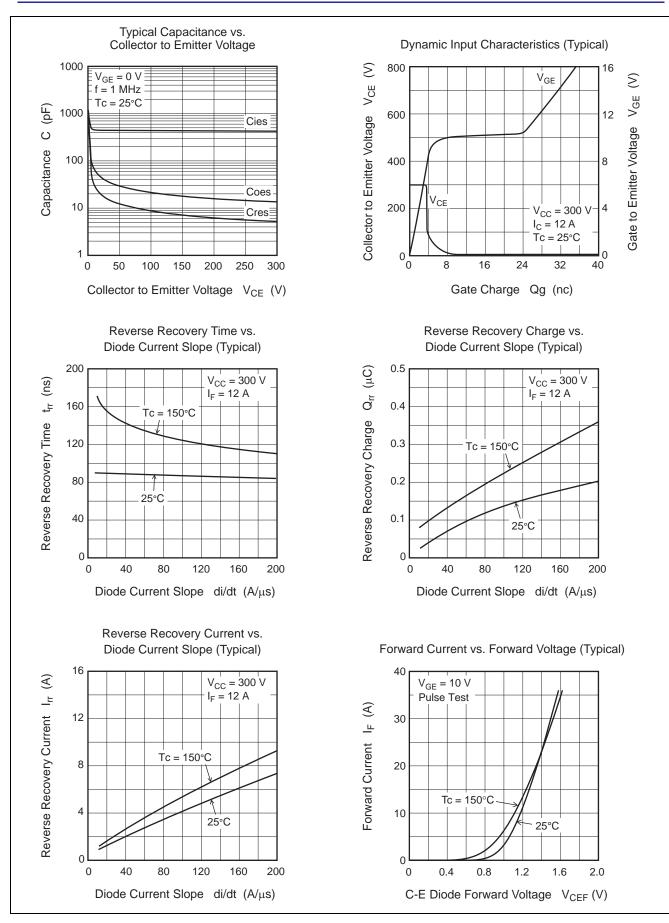




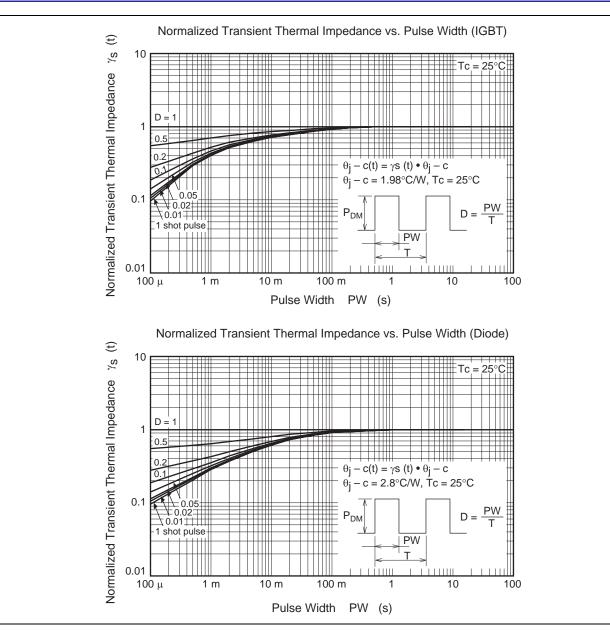




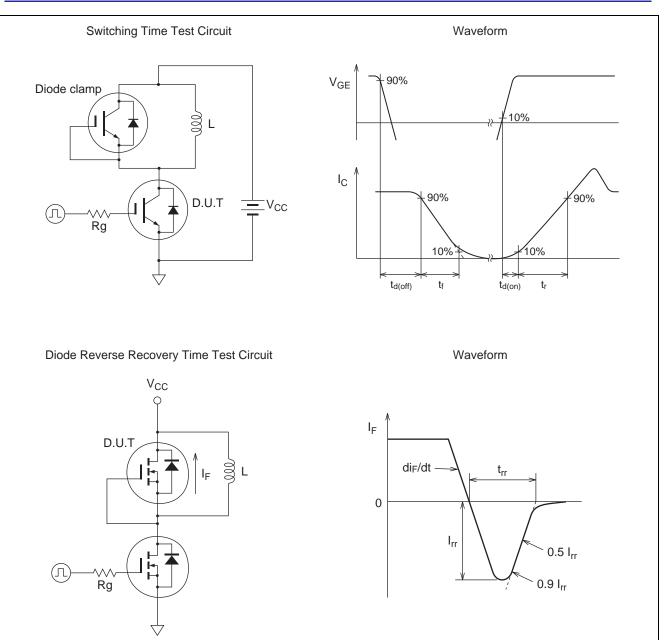






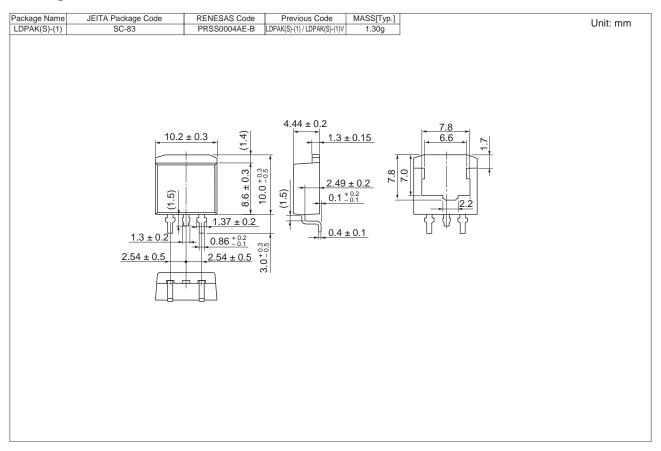








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60M2DPE-00#J3	1000 pcs	Taping



Notice

- Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 3. Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or
- technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
- 4. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from such alteration, modification, copy or otherwise misappropriation of Renesas Electronics product.
- Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.

*Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots etc.

"High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; and safety equipment etc.

Renesas Electronics products are neither intended nor authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems, surgical implantations etc.), or may cause serious property damages (nuclear reactor control systems, military equipment etc.). You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for which the product is not intended. Renesas Electronics shall not be in any way liable for any application for which the product is not intended by Renesas Electronics.

- 6. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 7. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or systems manufactured by vou.
- 8. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 9. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You should not use Renesas Electronics products or technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. When exporting the Renesas Electronics products or technology described in this document, you should comply with the applicable export control laws and regulations.
- It is the responsibility of the buyer or distributor of Renesas Electronics products, who distributes, disposes of, or otherwise places the product with a third party, to notify such third party in advance of the contents and conditions set forth in this document, Renesas Electronics assumes no responsibility for any losses incurred by you or third parties as a result of unauthorized use of Renesas Electronics products.
- 11. This document may not be reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.



SALES OFFICES

Refer to "http://www.renesas.com/" for the latest and detailed information

Renesas Electronics Corporation

http://www.renesas.com

 Renesas Electronics America Inc.

 2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.

 Tel: +1-408-588-6000, Fax: +1-408-588-6130

 Renesas Electronics Canada Limited

 1011 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada

 Tel: +1-905-898-5441, Fax: +1-905-898-3220

 Renesas Electronics Europe Limited

 Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K

 Tel: +44-1628-585-100, Fax: +444-1628-585-900

 Renesas Electronics Europe GmbH

 Arcadiastrasse 10, 40472 Disseldorf, Germany

 Tel: +92-11-65030, Fax: +449-11-6503-1327

 Renesas Electronics (Shanghal) Co., Ltd.

 Th Floor, Quantum Plaza, No. 27 ZhiChunLu Haidian District, Beijing 100083, P.R.China

 Tel: +96-155, Fax: +86-10-8235-1679

 Renesas Electronics (Shanghal) Co., Ltd.

 Unit 204, 205, AZIA Center, No. 1233 Lujiazui King Rd., Pudong District, Shanghai 200120, China

 Tel: +86-27587-1818, Fax: +86-22-887-7898

 Renesas Electronics Hong Kong Limited

 Unit 1001-1613, 16/FL, Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong

 Tel: +86-24-8175-9800, Fax: +8652-2886-9022/9044

 Renesas Electronics Taiwan Co., Ltd.

 13F, No. 383, Fu Shing Notth Road, Taipei, Taiwan

 Tel: +862-4175-9600, Fax: +8652-2886-9707

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Renesas Electronics: RJH60M2DPE-00#J3